
	<p>SIR172ADP-T1-GE3</p>
	<p>Hersteller-Teilenummer: SIR172ADP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 24A 8-SO</p> <p>Datenblätter:  SIR172ADP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10817 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIR172ADP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 24A 8-SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10817 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	3.9W (Ta), 29.8W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	24A (Tc)
Rds On (Max) @ Id, Vgs	8.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	44nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1515pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SIR172ADP-T1-GE3 ist neu im Original, Suche SIR172ADP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIR172ADP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIR172ADP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIR172DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 20A PPAK SO-8</p>	 <p>SIR168DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SIR172DP SI SIR172DP SI</p>	 <p>SIR172ADP Vishay Precision Group SIR172ADP VISHAY</p>
 <p>SIR172ADP-T1-E3 VISHAY VISHAY PAKSO-8</p>	 <p>SIR172DP-T1-E3 VISHAY SIR172DP-T1-E3 VISHAY</p>	 <p>SIR172DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 20A PPAK SO-8</p>	 <p>SIR172ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 24A 8-SO</p>

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|--|---|---|---|---|
|  SIR-563ST3FM |  SIR-563ST3FN |  SIR-563ST3FP |  SIR-563ST3FX |  SIR-56SB3F |
|  SIR-56ST3F |  SIR-59SSTA47 |  SIR11-21C/TR8 |  SIR15-21C/TR8 |  SIR158DP |
|  SIR158DP-T1-E3 |  SIR158DP-T1-GE3 |  SIR158DP-T1-GE3 |  SIR164ADP-T1-GE3 |  SIR164DP |
|  SIR164DP-T1-E3 |  SIR164DP-T1-GE3 |  SIR164DP-T1-GE3 |  SIR166DP |  SIR166DP-T1-E3 |
|  SIR166DP-T1-GE3 |  SIR166DP-T1-GE3 |  SIR168DP |  SIR168DP-T1-GE3 |  SIR168DP-T1-GE3 |
|  SIR172ADP-T1-GE3 |  SIR172DP |  SIR172DP-T1-E3 |  SIR172DP-T1-GE3 |  SIR172DP-T1-GE3 |
|  SIR330DP-T1-GE3 |  SIR330DP-T1-GE3 |  SIR402DP-T1-GE3 |  SIR402DP-T1-GE3 |  SIR403EDP-T1-GE3 |
|  SIR403EDP-T1-GE3 |  SIR404DP |  SIR404DP-T1-E3 |  SIR404DP-T1-GE3 |  SIR404DP-T1-GE3 |
|  SIR406DP |  SIR406DP-T1-E3 |  SIR406DP-T1-GE3 |  SIR406DP-T1-GE3 |  SIR406DP-T1-GE3-S |
|  SIR408DP-T1-GE3 |  SIR408DP-T1-GE3 |  SIR410DP-T1-E3 |  SIR410DP-T1-GE3 |  SIR410DP-T1-GE3 |

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